



Continental Device India Pvt. Limited

An IATF 16949, ISO9001 and ISO 14001 Certified Company



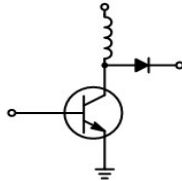
NPN Silicon Power Transistor

15 AMPERES, 400 and 450 VOLTS, 175 WATTS

BUX48 BUX48A



TO-3



TO-3

Metal Can Package

RoHS compliant

FEATURES:

The BUX 48/BUX 48A transistors are designed for high-voltage, high-speed, power switching in inductive circuits where fall time is critical. They are particularly suited for line-operated circuits.

Fast Turn-Off Times

60 ns Inductive Fall Time - 25° C (Typ)

120 ns Inductive Crossover Time - 25° C (Typ)

Operating Temperature Range -65 to +200° C

100° C Performance Specified for:

Reverse-Biased SOA with Inductive Loads

Switching Times with Inductive Loads

Saturation Voltage

Leakage Currents (125° C)

APPLICATIONS:

1. Switching Regulators
2. Inverters
3. Solenoid and Relay Drivers
4. Motor Controls
5. Deflection Circuits

BUX48 BUX48A
Rev0_02052020EM



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ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

Rating	Symbol	BUX48	BUX48A	Unit
Collector–Emitter Voltage	$V_{CEO(sus)}$	400	450	Vdc
Collector–Emitter Voltage ($V_{BE} = -1.5\text{ V}$)	V_{CEX}	850	1000	Vdc
Emitter Base Voltage	V_{EB}	7		Vdc
Collector Current — Continuous — Peak (1) — Overload	I_C I_{CM} I_{OI}	15 30 60		Adc
Base Current — Continuous — Peak (1)	I_B I_{BM}	5 20		Adc
Total Power Dissipation — $T_C = 25^\circ\text{C}$ — $T_C = 100^\circ\text{C}$ Derate above 25°C	P_D	175 100 1		Watts W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-65 to +200		$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	R_{JC}	1	$^\circ\text{C/W}$
Maximum Lead Temperature for Soldering Purposes: 1/8 from Case for 5 Seconds	T_L	275	$^\circ\text{C}$

(1) Pulse Test: Pulse Width = 5 ms, Duty Cycle $\leq 10\%$.



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ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$ unless otherwise specified)

Characteristic	Symbol	Min	Typ	Max	Unit
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OFF CHARACTERISTICS (1)

Collector–Emitter Sustaining Voltage (Table 1) ($I_C = 200\text{ mA}$, $I_B = 0$) $L = 25\text{ mH}$	BUX48 BUX48A	$V_{CEO(sus)}$	400 450	— —	— —	Vdc
Collector Cutoff Current ($V_{CEX} = \text{Rated Value}$, $V_{BE(off)} = 1.5\text{ Vdc}$) ($V_{CEX} = \text{Rated Value}$, $V_{BE(off)} = 1.5\text{ Vdc}$, $T_C = 125^\circ\text{C}$)		I_{CEX}	— —	— —	0.2 2	mAdc
Collector Cutoff Current ($V_{CE} = \text{Rated } V_{CEX}$, $R_{BE} = 10\ \Omega$)	$T_C = 25^\circ\text{C}$ $T_C = 125^\circ\text{C}$	I_{CER}	— —	— —	0.5 3	mAdc
Emitter Cutoff Current ($V_{EB} = 5\text{ Vdc}$, $I_C = 0$)		I_{EBO}	—	—	0.1	mAdc
Emitter–Base Breakdown Voltage ($I_E = 50\text{ mA}$ – $I_C = 0$)		$V_{(BR)EBO}$	7	—	—	Vdc

SECOND BREAKDOWN

Second Breakdown Collector Current with Base Forward Biased	$I_{S/b}$	See Figure 12	
Clamped Inductive SOA with Base Reverse Biased	RBSOA	See Figure 13	

ON CHARACTERISTICS (1)

DC Current Gain ($I_C = 10\text{ Adc}$, $V_{CE} = 5\text{ Vdc}$) ($I_C = 8\text{ Adc}$, $V_{CE} = 5\text{ Vdc}$)	BUX48 BUX48A	h_{FE}	8 8	— —	— —	
Collector–Emitter Saturation Voltage ($I_C = 10\text{ Adc}$, $I_B = 2\text{ Adc}$) ($I_C = 15\text{ Adc}$, $I_B = 3\text{ Adc}$) ($I_C = 10\text{ Adc}$, $I_B = 2\text{ Adc}$, $T_C = 100^\circ\text{C}$) ($I_C = 8\text{ Adc}$, $I_B = 1.6\text{ Adc}$) ($I_C = 12\text{ Adc}$, $I_B = 2.4\text{ Adc}$) ($I_C = 8\text{ Adc}$, $I_B = 1.6\text{ Adc}$, $T_C = 100^\circ\text{C}$)	BUX48 BUX48A	$V_{CE(sat)}$	— — — — — —	— — — — — —	1.5 5 2 1.5 5 2	Vdc
Base–Emitter Saturation Voltage ($I_C = 10\text{ Adc}$, $I_B = 2\text{ Adc}$) ($I_C = 10\text{ Adc}$, $I_B = 2\text{ Adc}$, $T_C = 100^\circ\text{C}$) ($I_C = 8\text{ Adc}$, $I_B = 1.6\text{ Adc}$) ($I_C = 8\text{ Adc}$, $I_B = 1.6\text{ Adc}$, $T_C = 100^\circ\text{C}$)	BUX48 BUX48A	$V_{BE(sat)}$	— — — —	— — — —	1.6 1.6 1.6 1.6	Vdc

DYNAMIC CHARACTERISTICS

Output Capacitance ($V_{CB} = 10\text{ Vdc}$, $I_E = 0$, $f_{test} = 1\text{ MHz}$)	C_{ob}	—	—	350	pF
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SWITCHING CHARACTERISTICS Resistive Load (Table 1)

Delay Time	$I_C = 10\text{ A}$, $I_B = 2\text{ A}$ $I_C = 8\text{ A}$, $I_B = 1.6\text{ A}$ Duty Cycle = 2%, $V_{BE(off)} = 5\text{ V}$ $T_p = 30\text{ s}$, $V_{CC} = 300\text{ V}$	BUX48 BUX48A	t_d	—	0.1	0.2	s
Rise Time			t_r	—	0.4	0.7	
Storage Time			t_s	—	1.3	2	
Fall Time			t_f	—	0.2	0.4	

Inductive Load, Clamped (Table 1)

Storage Time	$I_C = 10\text{ A}$ $I_{B1} = 2\text{ A}$	BUX48	$(T_C = 25^\circ\text{C})$	t_{sv}	—	1.3	—	s
Fall Time				t_{fi}	—	0.06	—	
Storage Time	$I_C = 8\text{ A}$ $I_{B1} = 1.6\text{ A}$	BUX48A	$(T_C = 100^\circ\text{C})$	t_{sv}	—	1.5	2.5	
Crossover Time				t_c	—	0.3	0.6	
Fall Time				t_{fi}	—	0.17	0.35	

(1) Pulse Test: Pulse Width = 300 μs , Duty Cycle $\leq 2\%$.

$V_{cl} = 300\text{ V}$, $V_{BE(off)} = 5\text{ V}$, $L_c = 180\text{ H}$

BUX48 BUX48A

Rev0_02052020EM

Table 1. Test Conditions for Dynamic Performance

	V _{CEO(sus)}	RBSOA AND INDUCTIVE SWITCHING	RESISTIVE SWITCHING
INPUT CONDITIONS	<p>PW Varied to Attain I_C = 200 mA</p>		<p>TURN-ON TIME I_{B1} adjusted to obtain the forced h_{FE} desired</p> <p>TURN-OFF TIME Use inductive switching driver as the input to the resistive test circuit.</p>
CIRCUIT VALUES	L _{coil} = 25 mH, V _{CC} = 10 V R _{coil} = 0.7	L _{coil} = 180 H R _{coil} = 0.05 V _{CC} = 20 V V _{clamp} = 300 V R _B ADJUSTED TO ATTAIN DESIRED I _{B1}	V _{CC} = 300 V R _L = 83 Pulse Width = 10 s
TEST CIRCUITS	<p>INDUCTIVE TEST CIRCUIT</p>	<p>OUTPUT WAVEFORMS</p> <p>t₁ Adjusted to Obtain I_C $t_1 \propto \frac{L_{coil} (I_{Cpk})}{V_{CC}}$ $t_2 \propto \frac{L_{coil} (I_{Cpk})}{V_{Clamp}}$</p> <p>Test Equipment Scope — Tektronix 475 or Equivalent</p>	<p>RESISTIVE TEST CIRCUIT</p>

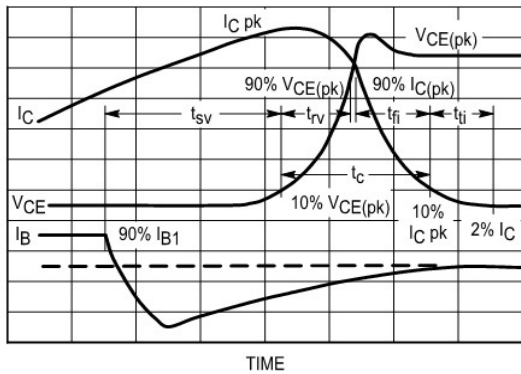


Figure 7. Inductive Switching Measurements

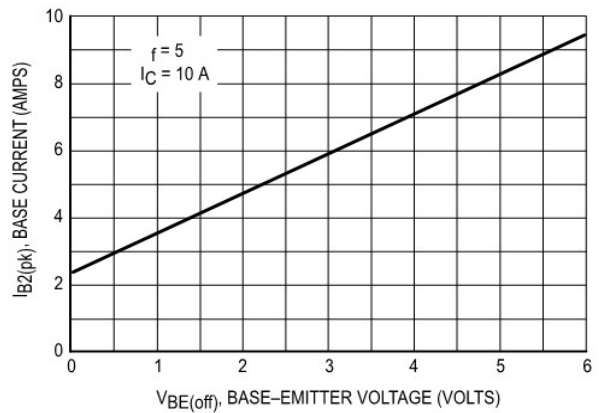


Figure 8. Peak-Reverse Current

INDUCTIVE SWITCHING

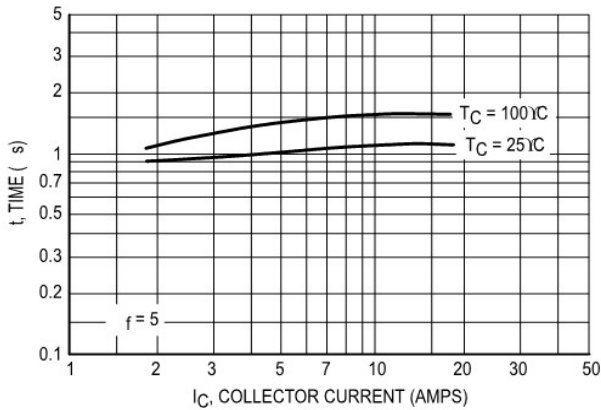


Figure 9. Storage Time, t_{sv}

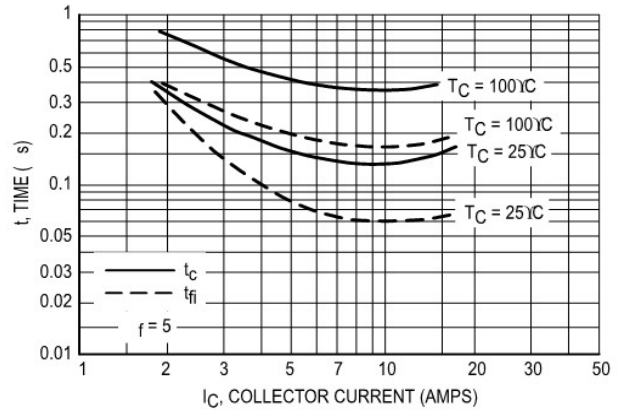


Figure 10. Crossover and Fall Times

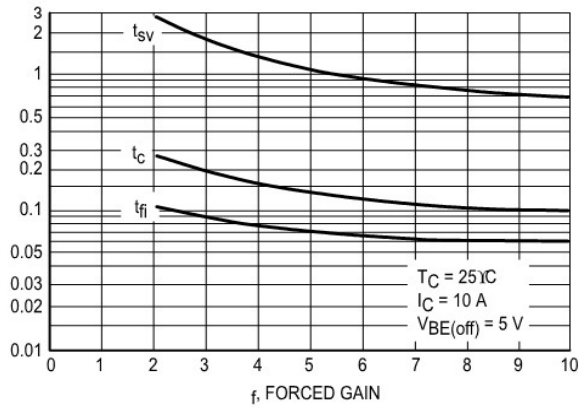


Figure 11a. Turn-Off Times versus Forced Gain

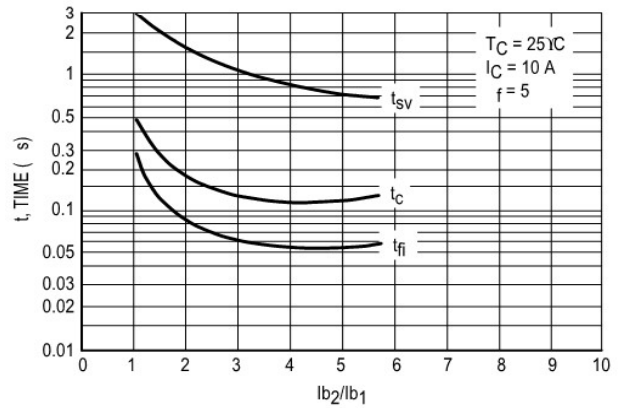


Figure 11b. Turn-Off Times versus I_{b2}/I_{b1}

Typical Characteristic Curves

The Safe Operating Area figures shown in Figures 12 and 13 are specified for these devices under the test conditions shown.

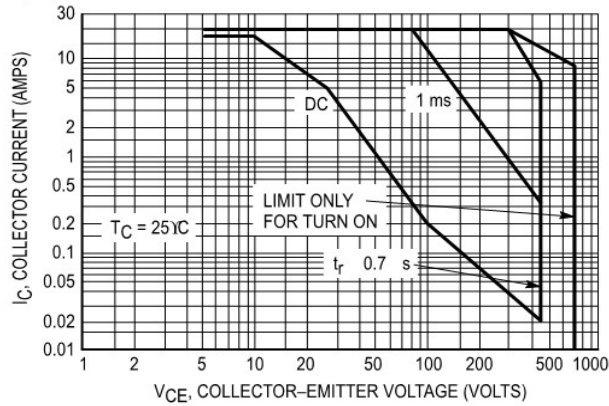


Figure 12. Forward Bias Safe Operating Area

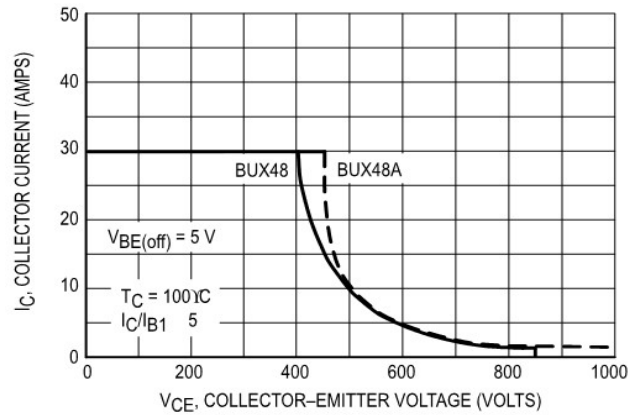


Figure 13. Reverse Bias Safe Operating Area

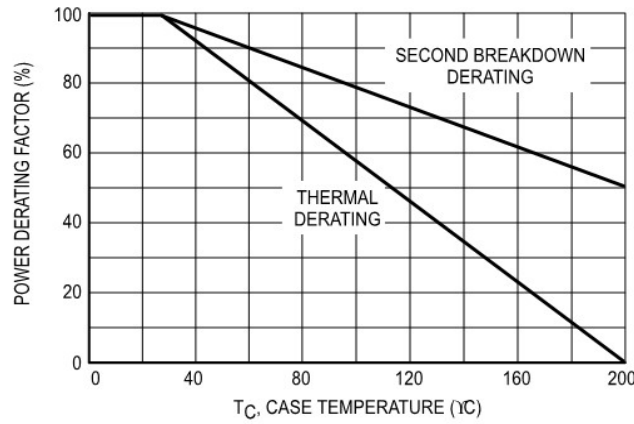


Figure 14. Power Derating

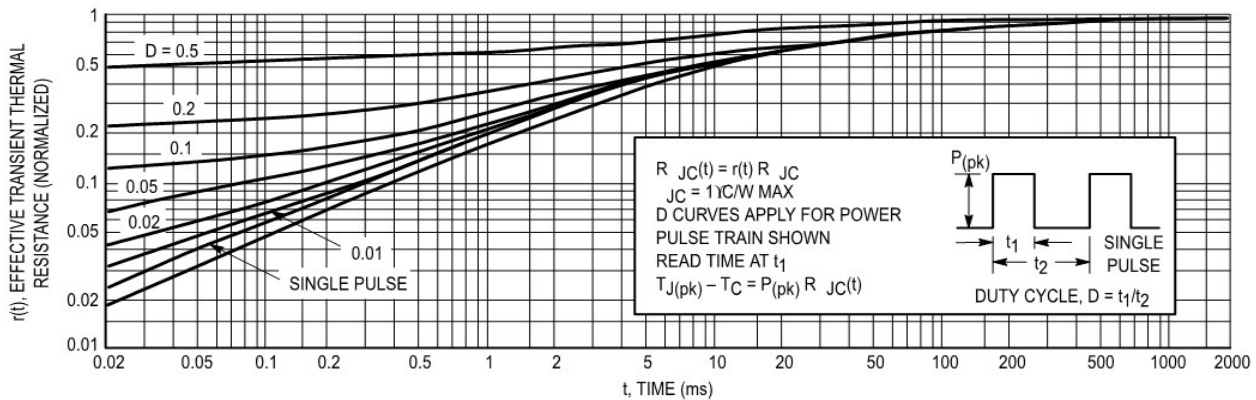


Figure 15. Thermal Response

Typical Characteristic Curves

OVERLOAD CHARACTERISTICS

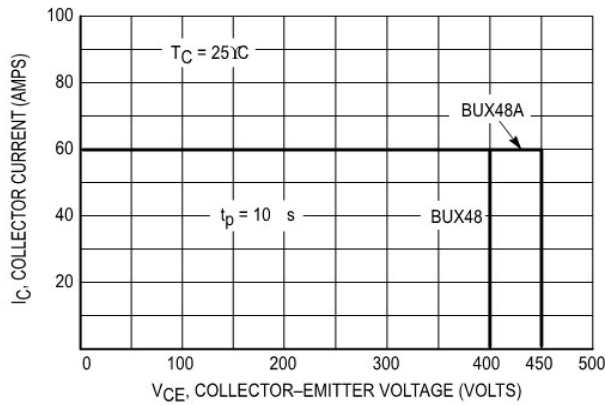


Figure 16. Rated Overload Safe Operating Area (OLSOA)

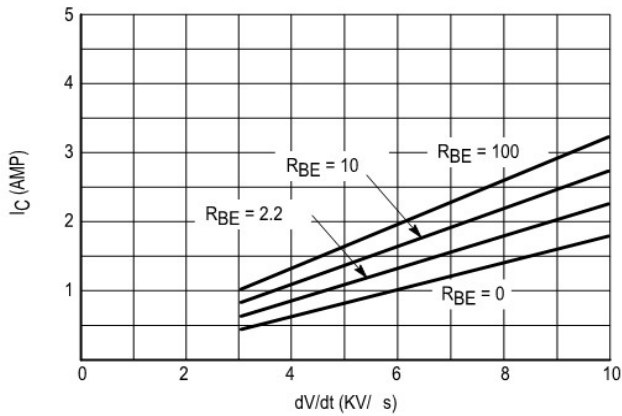


Figure 17. $I_C = f(dV/dt)$

Notes:

- ∞ $V_{CE} = V_{CC} + V_{BE}$
- ∞ Adjust pulsed current source for desired I_C, t_p

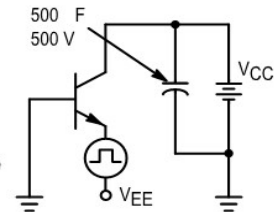
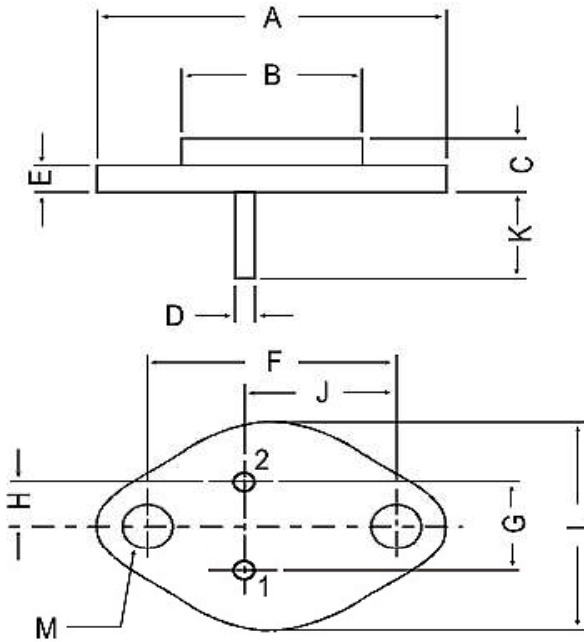


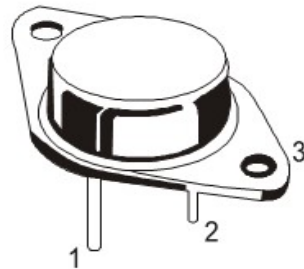
Figure 18. Overload SOA Test Circuit

Package Details



All dimensions in mm.

DIM	MIN.	MAX.
A	—	39.37
B	—	22.22
C	6.35	8.50
D	0.96	1.09
E	—	1.77
F	29.90	30.40
G	10.69	11.18
H	5.20	5.72
J	16.64	17.15
K	11.15	12.25
L	—	26.67
M	3.84	4.19



PIN CONFIGURATION

1. BASE
2. EMITTER
3. COLLECTOR

Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-3	100 pcs/pkt	1.3 kg/100 pcs	12.5" x 8" x 1.8"	0.1K	17" x 11.5" x 21"	2K	27.5 kgs



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Recommended Product Storage Environment for Discrete Semiconductor Devices

This storage environment assumes that the Diodes and transistors are packed properly inside the original packing supplied by CDIL.

- Temperature 5 °C to 30 °C
- Humidity between 40 to 70 %RH
- Air should be clean.
- Avoid harmful gas or dust.
- Avoid outdoor exposure or storage in areas subject to rain or water spraying .
- Avoid storage in areas subject to corrosive gas or dust. Product shall not be stored in areas exposed to direct sunlight.
- Avoid rapid change of temperature.
- Avoid condensation.
- Mechanical stress such as vibration and impact shall be avoided.
- The product shall not be placed directly on the floor.
- The product shall be stored on a plane area. They should not be turned upside down. They should not be placed against the wall.

Shelf Life of CDIL Products

The shelf life of products is the period from product manufacture to shipment to customers. The product can be unconditionally shipped within this period. The period is defined as 2 years.

If products are stored longer than the shelf life of 2 years the products shall be subjected to quality check as per CDIL quality procedure.

The products are further warranted for another one year after the date of shipment subject to the above conditions in CDIL original packing.

Floor Life of CDIL Products and MSL Level

When the products are opened from the original packing, the floor life will start.

For this, the following JEDEC table may be referred:

JEDEC MSL Level		
Level	Time	Condition
1	Unlimited	≤30 °C / 85% RH
2	1 Year	≤30 °C / 60% RH
2a	4 Weeks	≤30 °C / 60% RH
3	168 Hours	≤30 °C / 60% RH
4	72 Hours	≤30 °C / 60% RH
5	48 Hours	≤30 °C / 60% RH
5a	24 Hours	≤30 °C / 60% RH
6	Time on Label(TOL)	≤30 °C / 60% RH



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Customer Notes

Component Disposal Instructions

1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information.

Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

CDIL strives for continuous improvement and reserves the right to change the specifications of its products without prior notice.



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